**DISTINCTIVE FEATURES OF METAL/SUPERCONDUCTOR-INSULATOR TRANSITIONS IN DOPED *La*-BASED CUPRATES WITH LARGE-RADIUS IMPURITIES**

*Dzhumanov S.1, Kurbanov U.T.1,2, Zhumabaeva G.K.1*

1Institute of Nuclear Physics, Uzbek Academy of Sciences Ulugbek, Tashkent 100214, Uzbekistan;

e-mail: ukurbanov@inp.uz

2Tashkent State Technical University named after Islam Karimov, Tashkent 100095, Uzbekistan

In polar materials, lattice vibrations (acoustic and optical phonons) and hole carriers interacting with lattice defects (e.g., dopants or impurities) can be self-trapped near defects and in a defect-free deformable lattice. In the localization of charge carriers and metal/superconductor-insulator transitions in hole-doped cuprates, the role of large and small radius dopants (impurities), carrier-defect-lattice and carrier-lattice interactions is of more importance [1]. In doped La-based cuprates with small-radius impurities, metal-insulator transitions arising from two types interactions mentioned above will occur over a wide doping range from lightly doped to heavily doped states [2]. However, in doped La-based cuprates with large-radius dopants, it is not obvious which interactions will dominate and cause the metal/superconductor-insulator transitions [3].

In this work, we study the possibility of the localization of hole carriers and the distinctive features of the metal/superconductor-insulator transitions in doped La-based cuprates with large-radius dopants (impurities) within the single-carrier cuprate superconductor model. We show that when the value of the high-frequency dielectric constant *ε*∞ changes from 5 to 2.5 the new metal/superconductor-insulator transitions in doped cuprates La2−xSrxCuO4 (LSCO) and La2−xBaxCuO4 (LBCO) are caused by the strong hole-lattice interactions and polaronic effects and occur in a wide doping range from the lightly doped to strongly overdoped regime. We find that such metal/superconductor-insulator transitions depending on the values of *ε*∞ and η= *ε*∞/ *ε*0 (e.g., for *ε*∞ ≥2.5 and η≥0.02) and the types of charge ordering occur in these materials in the strongly overdoped regime (when the binding energy *Ep* of large polarons is increased significantly from 0.05 eV (at *ε*∞ =5) up to 0.2 eV (at *ε*∞ =2.5)), as observed experimentally in ARPES studies [4]. Our theoretical results for metal/superconductor-insulator transitions in doped La-based cuprates are in good agreement with the experimental findings.

**References**

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